## NSN 5962-01-366-4315

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Features Provided:
Electrostatic sensitive and programmed
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Product Name:
Fuse prom
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0